#### DESCRIPTION

The ULN2803/2804 series are high-voltage, high-current darington arrays comprised of eight NPN darington

pairs. All units feature integral clamp diodes for switching inductive loads.

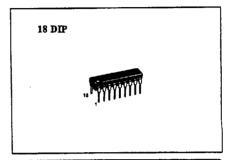
#### FEATURES

- Output current......500mA
- High Sustaining Voltage.....50V Min.
- · Output Clamp Diode
- Inputs Compatible With Various Types of Logic

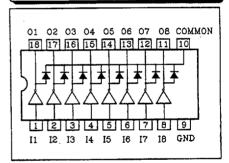
Туре	Input Resistor	Designation
ULN2803	2.7ΚΩ	TTL, 5V C - MOS
ULN2804	10.5KΩ	6~15V P-MOS, C-MOS

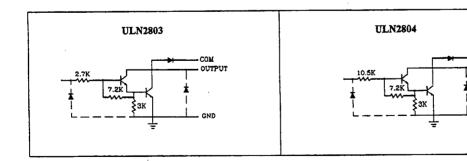
#### MAXIMUM RATING(Ta=25 tunless otherwise

Che	racteristic	Symbol	Rating	Unit
Output Sustaining		V <sub>CE(SUS)</sub>	50	V
Voltage			<u> </u>	
Output Current		Iout	500	m.A
Input Voltage		V <sub>IN</sub> .	-0.5~+30	V
Input Current		I <sub>IN</sub> .	25	πA
Clamp	Reverse Voltage	V <sub>R</sub>	50	V
Diode	Forward Current	I <sub>F</sub>	500	mA
GND Terminal Current		$I_{GND}$	3.2	A
Power Dissipation		$P_{D}$	1.47	W
Operating Temperature		Торг	-40~85	℃
Storage Temperature		Tstg	-55~150	℃



#### PIN CONNECTION (TOP VIEW)







### RECOMMENDED OPERATING CONDITIONS(Ta=-40-85 t)

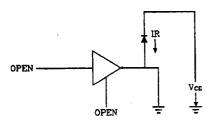
CHARACTERISTIC	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Output Sustaining Voltage	V <sub>CE(SUS)</sub>		0		50	V
Output Current	I <sub>out</sub>	T <sub>PW</sub> =25mS,DF=8%, 8 Circuits	0	-	400	mA
		T <sub>Pw</sub> =25mS,DF=25% 8 Circuits	0	-	200	
Input Voltage	V <sub>IN</sub>		0	-	30	v
Clamp Diode Reverse Voltage	V <sub>R</sub>		T -	-	50	V
Clamp Diode Forword Current	I <sub>F</sub>		· -	-	400	mA
Power Dissipation	$P_{D}$		<del>-</del>	-	0.52	w

## ELECTRICAL CHARACTERISTICS(Ta=25% unless otherwise noted)

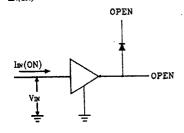
CHARAC	TERISTIC	SYMBOL	Test Circuit	CONDITION	MIN.	TYP.	MAX	UNI
Ontout look Co.		,		V <sub>CE</sub> =50V, Ta=25℃	-	-	50	
Output leak Cur		I <sub>CEX</sub>	ì	V <sub>CE</sub> =50V, Ta=85℃	-		100	μА
<del></del>	ULN2804	<del> </del>		$V_{CE}$ =50V, $V_{Di}$ =1V	-	-	500	
G-11 5- 1		1		I <sub>OUT</sub> =350mA, I <sub>IN</sub> =500μ A	-	1.3	1.6	
Collector-Emitt		V <sub>CE(set)</sub>	2	I <sub>OUI</sub> =200mA, I <sub>IN</sub> =350 μ. A	-	1.1	1.3	v
Saturation Volt				I <sub>OUT</sub> =100mA, I <sub>IN</sub> =250 μ A	-	0.9	1.1	1 :
Input Current	ULN2803	I <sub>IN(on)</sub>		V <sub>IN</sub> =3.85V	-	0.93	1.35	1
	ULN2804	ļ		V <sub>IN</sub> =5V	-	0.35	0.5	mA
	1			V <sub>IN</sub> =12V		1.0	1.45	1
	<u> </u>	I <sub>ON(OFF)</sub>	4	I <sub>OUT</sub> =500 μ A, Ta=85 ℃	50	65	-	μА
				V <sub>CE</sub> =2V, I <sub>OUT</sub> =200mA	-	-	2.4	
	ULN2803			V <sub>CE</sub> =2V, I <sub>OUT</sub> =250mA	-	-	2.7	1
Input Voltage				V <sub>CE</sub> =2V, I <sub>OUT</sub> =300mA	-	-	3.0	ĺν
	ULN2804	V <sub>IN(ON)</sub>	5	$V_{CE}=2V$ , $I_{OUT}=125mA$	-	-	5.0	1
	1		1	$V_{CE}=2V$ , $I_{OUT}=200mA$	-	-	6.0	1
	1			$V_{CE}=2V$ , $I_{OUT}=275$ mA	-	<b>-</b>	7.0	1
	<u> </u>			V <sub>CE</sub> =2V, I <sub>OUT</sub> =350mA	-	-	8.0	1
DC Current Tra		h <sub>FE</sub>	2	V <sub>CE</sub> =2V, I <sub>OUT</sub> =350mA	1000	-	1 .	<del> </del>
Clamp Diode R	everse Current	IE	6	V <sub>R</sub> =50V, Ta=25℃	•	-	50	шА
			}	V <sub>R</sub> =50V, Ta=85℃	<del>  .                                     </del>	-	100	<b>"</b>
Clamp Diode F	orward Voltage	V <sub>F</sub>	7	I <sub>r</sub> =350mA			2.0	l v
Input Capacitar	nce	C <sub>IN</sub>			<del> </del>	15	2.0	DF
Turn-On Delay		· ton	8	$V_{0UI} = 50 V_{.} R_{.} = 163 \Omega$	<del>                                     </del>	0.1	<del>  -</del>	μS
Turn-Off Delay	,	torr	1	C <sub>L</sub> =15 pF	<del>-</del>	0.1	<del>                                     </del>	ا سام

### TEST CIRCUIT

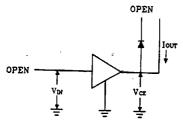
#### $1. I_{CEX}$



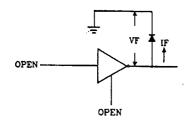
### 3. EN(ON)



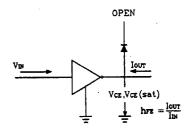
### 5. VIN(ON)



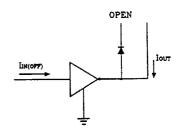
### 7. V<sub>F</sub>



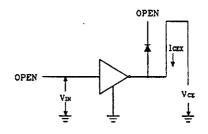
### $2.\;V_{\text{CE(sat)}},\;h_{\text{FE}}$



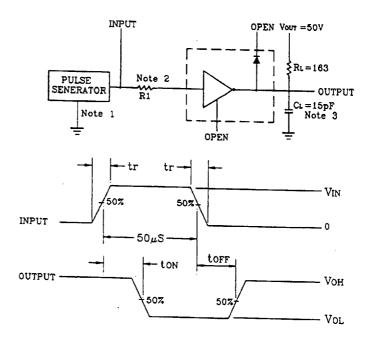
### 4. IN(OFF)



### 6. I<sub>R</sub>



### 8. ton, toff



Notes: 1. Pulse Width  $50\,\mu$  s, Duty Cycle 10% Output Impedance  $50\,\Omega$ 

 $t_r \leq 5$ ns,  $t_f \leq 10$ ns

2. See below

**Input Conditions** 

TYPE NUMBER	$R_I$	VIH
ULN2803	0	3V
ULN2804	0	8V

3. C<sub>L</sub> includes prob and jig capacitance.

